

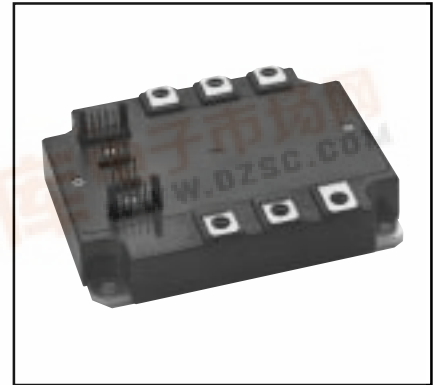
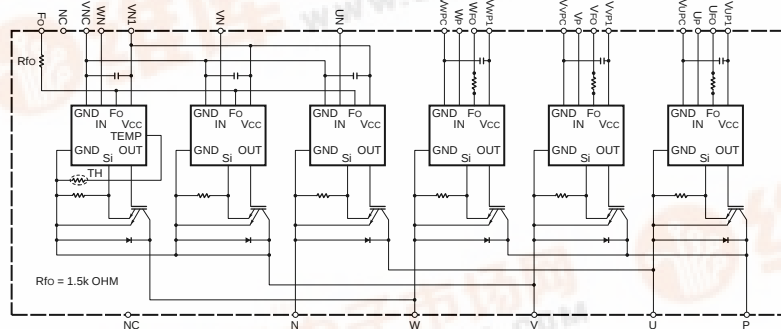
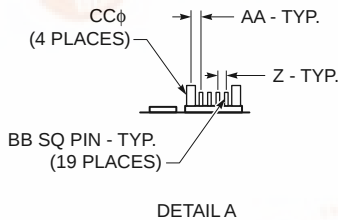
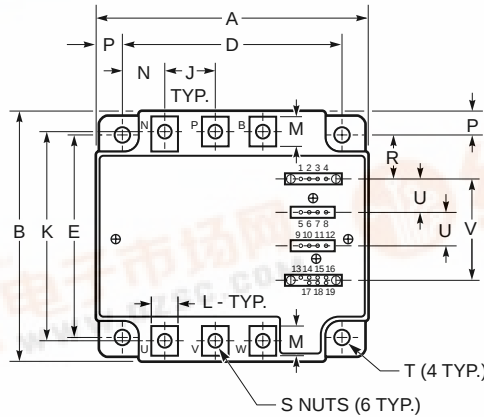
MITSUBISHI INTELLIGENT POWER MODULES

PM100CVA060

FLAT-BASE TYPE
INSULATED PACKAGE

TERMINAL CODE

- | | |
|----------|----------|
| 1. WFO | 11. Up |
| 2. VWPC | 12. VUP1 |
| 3. Wp | 13. Br |
| 4. VWP1 | 14. Fo |
| 5. VFO | 15. VNC |
| 6. VVPC | 16. VN1 |
| 7. Vp | 17. UN |
| 8. VVP1 | 18. VN |
| 9. UFO | 19. WN |
| 10. VUPC | |



Description:

Mitsubishi Intelligent Power Modules are isolated base modules designed for power switching applications operating at frequencies to 20kHz. Built-in control circuits provide optimum gate drive and protection for the IGBT and free-wheel diode power devices.

Features:

- ☐ Complete Output Power Circuit
- ☐ Gate Drive Circuit
- ☐ Protection Logic
 - Short Circuit
 - Over Temperature
 - Under Voltage

Applications:

- ☐ Inverters
- ☐ UPS
- ☐ Motion/Servo Control
- ☐ Power Supplies

Ordering Information:

Example: Select the complete part number from the table below -i.e. PM100CVA060 is a 600V, 100 Ampere Intelligent Power Module.

Type	Current Rating Amperes	V _{CES} Volts (x 10)
PM	100	60

Outline Drawing and Circuit Diagram

Dimensions	Inches	Millimeters
A	4.33	110.0
B	3.50	89.0
C	0.87 +0.04/-0.02	22.0 +1.0/-0.5
D	3.74±0.010	95.0±0.25
E	2.91±0.010	74.0±0.25
F	0.16	4.0
G	0.87	22.0
H	0.42	10.6
J	0.79	20.0
K	2.99±0.02	76.0±0.5
L	0.39	10.0
M	0.49	12.5
N	0.67	17.0

Dimensions	Inches	Millimeters
P	0.30	7.5
R	0.65	16.5
S	M5 Metric	M5
T	0.22 Dia.	Dia. 5.5
U	0.56±0.010	14.1±0.25
V	1.72±0.012	43.57±0.3
W	0.57±0.012	14.6±0.3
X	2.90	73.7
Y	0.78	19.7
Z	0.10±0.010	2.54±0.25
AA	1.37±0.010	3.49±0.25
BB	0.02 SQ	0.64 SQ
CC	0.12 +0.04/-0.02	3.0 +1.0/-0.5

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Absolute Maximum Ratings, $T_j = 25^\circ\text{C}$ unless otherwise specified

Ratings	Symbol	PM100CVA060	Units
Power Device Junction Temperature	T_j	-20 to 150	$^\circ\text{C}$
Storage Temperature	T_{stg}	-40 to 125	$^\circ\text{C}$
Case Operating Temperature	T_C	-20 to 100	$^\circ\text{C}$
Mounting Torque, M5 Mounting Screws	—	2.5~3.5	N · m
Mounting Torque, M5 Main Terminal Screws	—	2.5~3.5	N · m
Module Weight (Typical)	—	560	Grams
Supply Voltage, Surge (Applied between P - N, Surge Value)	$V_{\text{CC(surge)}}$	500	Volts
Supply Voltage Protected by SC ($V_D = 13.5 \sim 16.5\text{V}$, Inverter Part, $T_j = 125^\circ\text{C}$ Start)	$V_{\text{CC(prot.)}}$	400	Volts
Isolation Voltage (Main Terminal to Baseplate, AC 1 min.)	V_{iso}	2500	Vrms

Control Sector

Supply Voltage (Applied between $V_{\text{UP1}}\text{-}V_{\text{UPC}}$, $V_{\text{VP1}}\text{-}V_{\text{VPC}}$, $V_{\text{WP1}}\text{-}V_{\text{WPC}}$, $V_{\text{N1}}\text{-}V_{\text{NC}}$)	V_D	20	Volts
Input Voltage (Applied between $U_P\text{-}V_{\text{UPC}}$, $V_P\text{-}V_{\text{VPC}}$, $W_P\text{-}V_{\text{WPC}}$, $U_N \cdot V_N \cdot W_N\text{-}V_{\text{NC}}$)	V_{CIN}	20	Volts
Fault Output Supply Voltage (Applied between $F_O\text{-}V_{\text{NC}}$, $*F_O\text{-}V_{*PC}$)	V_{FO}	20	Volts
Fault Output Current (Sink Current at U_{FO} , V_{FO} , W_{FO} and F_O Terminal)	I_{FO}	20	mA

IGBT Inverter

Collector-Emitter Voltage ($V_D = 15\text{V}$, $V_{\text{CIN}} = 15\text{V}$)	V_{CES}	600	Volts
Collector Current, ($T_C = 25^\circ\text{C}$)	I_C	100	Amperes
Peak Collector Current, ($T_C = 25^\circ\text{C}$)	I_{CP}	200	Amperes
Collector Dissipation ($T_C = 25^\circ\text{C}$)	P_C	338	Watts

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Electrical and Mechanical Characteristics, $T_j = 25^\circ\text{C}$ unless otherwise specified

Characteristics	Symbol	Test Conditions	Min.	Typ.	Max.	Units
Control Sector						
Short Circuit Trip Level	SC	$-20^\circ\text{C} \leq T_j \leq 125^\circ\text{C}$, $V_D = 15\text{V}$	158	—	—	Amperes
Short Circuit Current Delay Time	$t_{\text{off(SC)}}$	$V_D = 15\text{V}$	—	10	—	μs
Over Temperature Protection	OT	Trip Level	100	110	120	$^\circ\text{C}$
($V_D = 15\text{V}$)	OT_r	Reset Level	85	95	105	$^\circ\text{C}$
Supply Circuit Under Voltage Protection	UV	Trip Level	11.5	12.0	12.5	Volts
($-20^\circ\text{C} \leq T_j \leq 125^\circ\text{C}$)	UV_r	Reset Level	—	12.5	—	Volts
Circuit Current	I_D	$V_D = 15\text{V}$, $V_{\text{CIN}} = 15\text{V}$, $V_{\text{N1}}-V_{\text{NC}}$	—	40	55	mA
		$V_D = 15\text{V}$, $V_{\text{CIN}} = 15\text{V}$, $V_{\text{XP1}}-V_{\text{XPC}}$	—	13	18	mA
Input ON Threshold Voltage	$V_{\text{th(on)}}$	Applied between U_P-V_{UPC} , V_P-V_{VPC} ,	1.2	1.5	1.8	Volts
Input OFF Threshold Voltage	$V_{\text{th(off)}}$	W_P-V_{WPC} , $U_N \cdot V_N \cdot W_N-V_{\text{NC}}$	1.7	2.0	2.3	Volts
Fault Output Current	$I_{\text{FO(H)}}$	$V_D = 15\text{V}$, $V_{\text{FO}} = 15\text{V}$	—	—	0.01	mA
	$I_{\text{FO(L)}}$	$V_D = 15\text{V}$, $V_{\text{FO}} = 15\text{V}$	—	10	15	mA
Minimum Fault Output Pulse Width	t_{FO}	$V_D = 15\text{V}$	1.0	1.8	—	ms

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Electrical and Mechanical Characteristics, $T_j = 25^\circ\text{C}$ unless otherwise specified

Characteristics	Symbol	Test Conditions	Min.	Typ.	Max.	Units
IGBT Inverter Sector						
Collector-Emitter Cutoff Current	I_{CES}	$V_{CE} = V_{CES}, V_D = 15\text{V}, T_j = 25^\circ\text{C}$	—	—	1.0	mA
		$V_{CE} = V_{CES}, V_D = 15\text{V}, T_j = 125^\circ\text{C}$	—	—	10.0	mA
FWDi Forward Voltage	V_{EC}	$-I_C = 100\text{A}, V_D = 15\text{V}, V_{CIN} = 15\text{V}$	—	2.20	3.30	Volts
Collector-Emitter Saturation Voltage	$V_{CE(sat)}$	$V_D = 15\text{V}, V_{CIN} = 0\text{V}, I_C = 100\text{A},$ Pulsed, $T_j = 25^\circ\text{C}$	—	2.35	2.80	Volts
		$V_D = 15\text{V}, V_{CIN} = 0\text{V}, I_C = 100\text{A},$ Pulsed, $T_j = 125^\circ\text{C}$	—	2.55	3.05	Volts
Inductive Load Switching Time	t_{on}		0.4	0.8	2.1	μs
	t_{rr}	$V_D = 15\text{V}, V_{CIN} = 0\text{V} \leftrightarrow 15\text{V}$	—	0.2	0.3	μs
	$t_{C(on)}$	$V_{CC} = 300\text{V}, I_C = 100\text{A},$ $T_j = 125^\circ\text{C}$	—	0.3	1.1	μs
	t_{off}		—	1.8	2.9	μs
	$t_{C(off)}$	(Per 1 arm) Inductive Load	—	0.6	1.2	μs

Thermal Characteristics

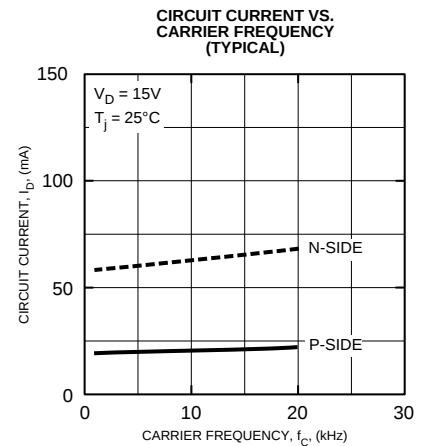
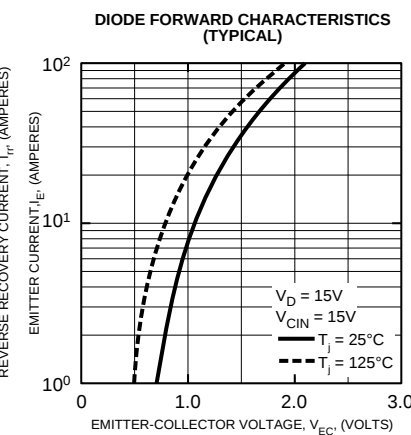
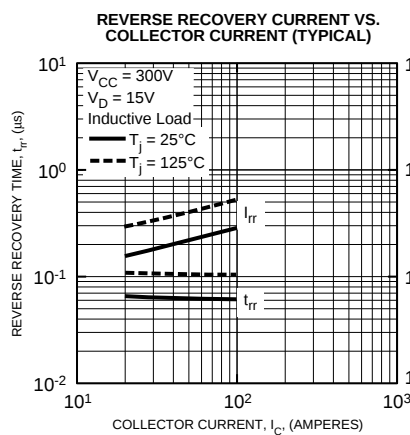
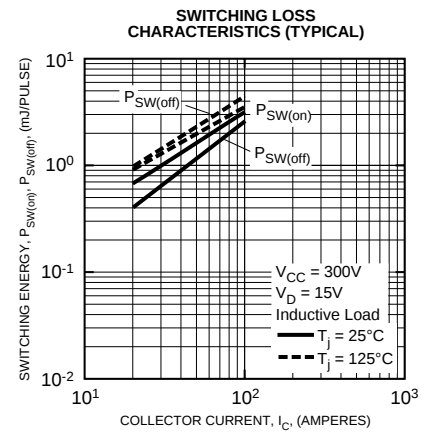
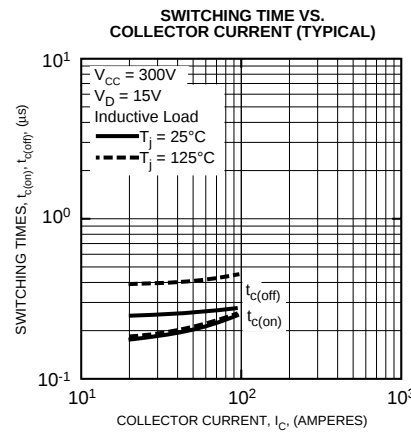
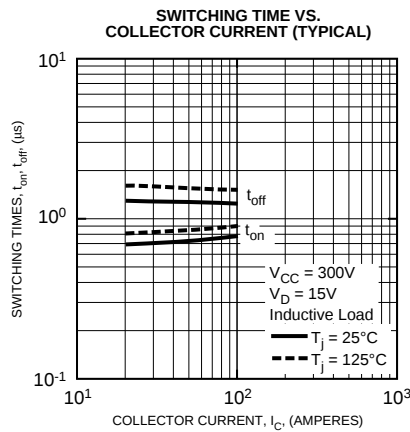
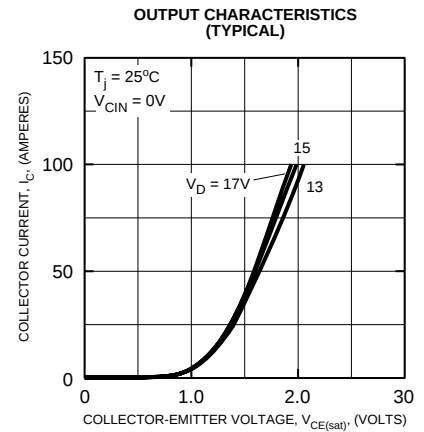
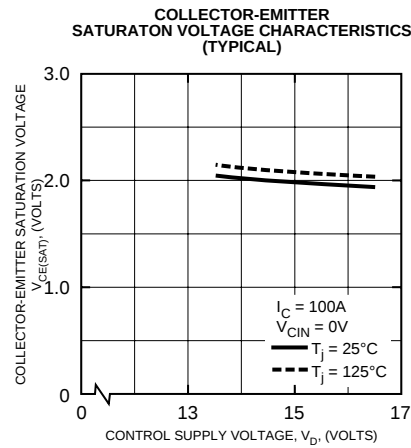
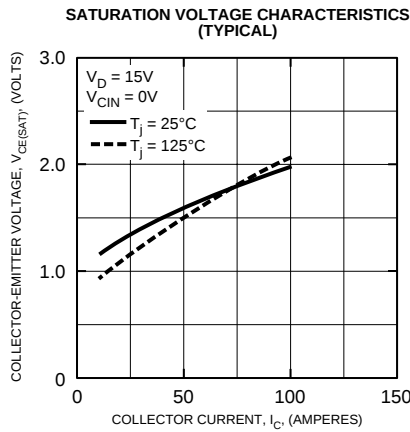
Characteristic	Symbol	Condition	Min.	Typ.	Max.	Units
Junction to Case Thermal Resistance	$R_{th(j-c)Q}$	Each Inverter IGBT	—	—	0.37	$^\circ\text{C/Watt}$
	$R_{th(j-c)F}$	Each Inverter FWDi	—	—	0.70	$^\circ\text{C/Watt}$
Contact Thermal Resistance	$R_{th(c-f)}$	Case to Fin Per Module, Thermal Grease Applied	—	—	0.027	$^\circ\text{C/Watt}$

Recommended Conditions for Use

Characteristic	Symbol	Condition	Value	Units
Supply Voltage	V_{CC}	Applied across P-N Terminals	≤ 400	Volts
	$V_{CE(surge)}$	Applied across Terminals P-U, P-V, P-W, U-N, V-N, W-N	≤ 500	Volts
	V_D	Applied between V_{UP1} - V_{UPC} , V_{VP1} - V_{VPC} , V_{WP1} - V_{WPC} , V_{N1} - V_{NC}	15 ± 1.5	Volts
Input ON Voltage	$V_{CIN(on)}$	Applied between U_P - V_{UPC} , V_P - V_{VPC} , W_P - V_{WPC} , U_N · V_N · W_N - V_{NC}	≤ 0.8	Volts
Input OFF Voltage	$V_{CIN(off)}$		≥ 4.0	Volts
Arm Shoot-Through Blocking Time	t_{dead}	For IPM's each Input Signal	≥ 2.5	μs

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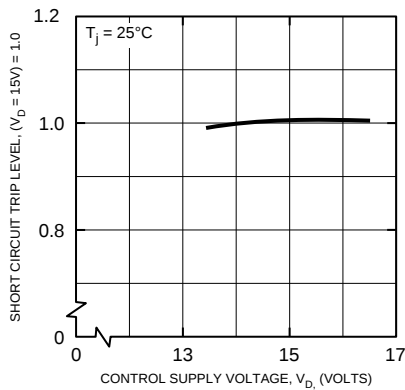
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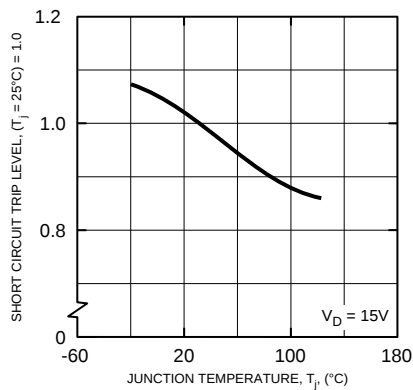
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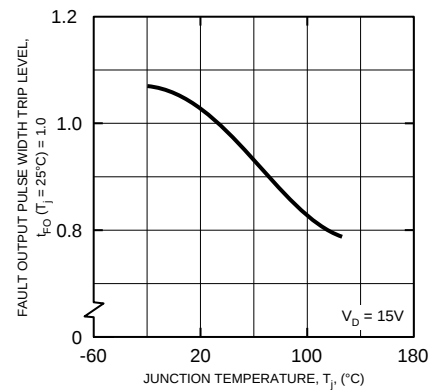
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SUPPLY VOLTAGE (TYPICAL)



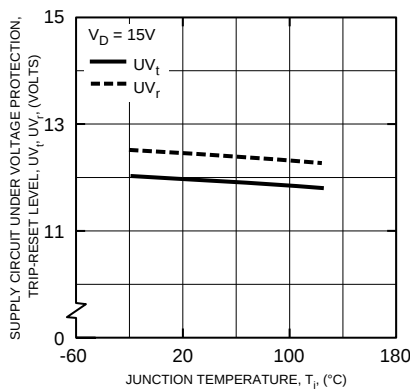
OVER CURRENT TRIP LEVEL
TEMPERATURE DEPENDENCY
(TYPICAL)



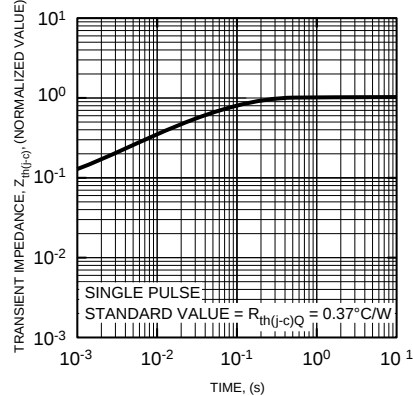
FAULT OUTPUT PULSE WIDTH VS.
TEMPERATURE (TYPICAL)



CONTROL SUPPLY VOLTAGE TRIP-RESET
LEVEL TEMPERATURE DEPENDENCY
(TYPICAL)



TRANSIENT THERMAL
IMPEDANCE CHARACTERISTICS
(Each IGBT)



TRANSIENT THERMAL
IMPEDANCE CHARACTERISTICS
(Each FWDi)

